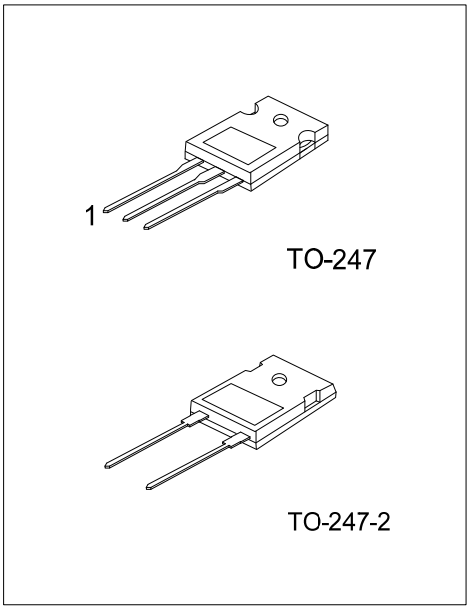
FAST RECOVERY DIODE



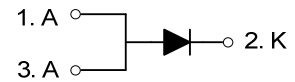
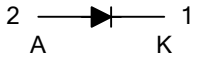
■ DESCRIPTION

The UTC **UFR10060** is a superfast recovery rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop, low leakage, high current capability and high surge capability etc. These characteristics make it ideal for heavy duty applications that demand long term reliability. also fit into auxiliary functions such as snubber, bootstrap, and demagnetization applications.

■ FEATURES

* Planar Technique
* High Switch Speed
* High Reliability

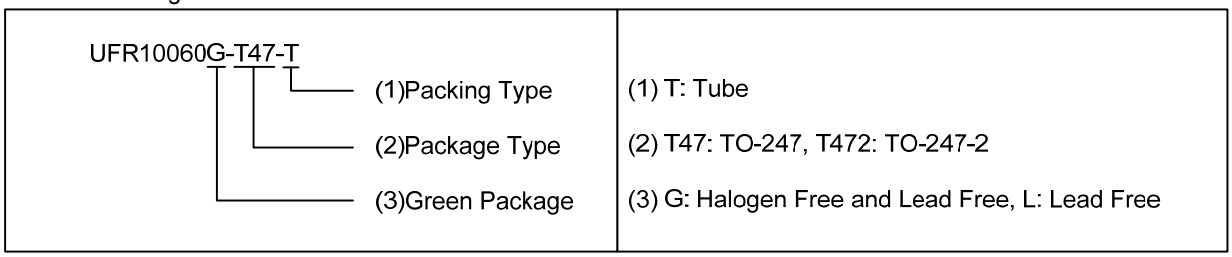
■ SYMBOL

TO-247	TO-247-2
	

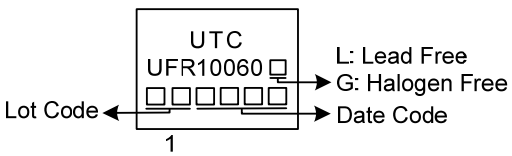
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UFR10060L-T47-T	UFR10060G-T47-T	TO-247	A	K	A	Tube
UFR10060L-T472-T	UFR10060G-T472-T	TO-247-2	K	A	-	Tube

Note: Pin Assignment: G: Gate D: Drain S: Source



■ MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

Ratings at 25°C ambient temperature unless otherwise specified. Resistive or inductive load, 60Hz.

PARAMETER		SYMBOL	RATINGS	UNIT
Repetitive Peak Reverse Voltage		V_{RRM}	600	V
Average forward current, δ= 0.5%	T_C=130°C	$I_{F(AV)}$	100	A
Surge non repetitive forward current	t_P=10ms Sinusoidal	I_{FSM}	250	A
Operating Junction Temperature		T_J	+150	°C
Storage Temperature Range		T_{STG}	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θ_{JC}	0.8	°C/W

■ ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Resistive or inductive load, 60Hz

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Forward voltage drop (Note 1)	V_F	I_F=100A	T_J=25°C			1.7	V
			T_J=125°C			1.6	V
Maximum Reverse Leakage Current (Note 2)	I_R	V_R=V_{RRM}	T_J=25°C			100	μA
			T_J=125°C			500	μA
Reverse recovery time	t_{rr}	I_F=1.0A,V_R=30V, dI_F/dt=200A/μs, T_J=25°C			34		ns
		I_F=30A,V_R=30V, dI_F/dt=200A/μs T_J=25°C			64		ns
Reverse Recovery Time	t_{rr}	I_F=30A,V_R=400V, dI_F/dt=300A/μs T_J=125°C			126		ns
Reverse Recovery Charge	Q_{rr}				1.62		nC
Peak Reverse Recovery Current	I_{RR}				20.7		A

Notes: 1. Pulse test: t_P = 380 ms, δ= 2 %.
2. Pulse test: t_P = 5 ms, δ= 2 %.
3. To evaluate the conduction losses use the following equation: $P=1.4 \times I_{F(AV)} + 0.027\ I_F^2$ (RMS).